SHANGHAI SUNRISE ELECTRONICS CO., LTD.

US1A THRU US1M
SURFACE MOUNT ULTRA
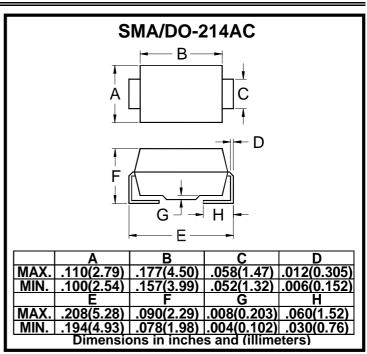## FAST SWITCHING RECTIFIER

TECHNICAL SPECIFICATION

VOLTAGE: 50 TO 1000V CURRENT: 1.0A

FEATURES

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- Glass passivated chip
- Ultra fast recovery for high efficiency
- High temperature soldering guaranteed: $260^oC/10sec/$at terminal

MECHANICAL DATA

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode

SMA/DO-214AC

	A	B	C	D
MAX.	.110(2.79)	.177(4.50)	.058(1.47)	.012(0.305)
MIN.	.100(2.54)	.157(3.99)	.052(1.32)	.006(0.152)
	E	F	G	H
MAX.	.208(5.28)	.090(2.29)	.008(0.203)	.060(1.52)
MIN.	.194(4.93)	.078(1.98)	.004(0.102)	.030(0.76)

Dimensions in inches and (illimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25^oC, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	US 1A	US 1B	US 1D	US 1G	US 1J	US 1K	US 1M	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current ($T_L=100^oC$)	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage (at rated forward current)	V_F	1.0			1.4		1.7		V
Maximum DC Reverse Current $T_a=25^oC$	I_R	5.0							µA
(at rated DC blocking voltage) $T_a=100^oC$		200							µA
Maximum Reverse Recovery Time (Note 1)	trr	50				75			nS
Typical Junction Capacitance (Note 2)	C_J	20				10			pF
Typical Thermal Resistance (Note 3)	$R_θ(ja)$	32							$^oC/W$
Storage and Operation Junction Temperature	T_{STG},T_J	-50 to +150							^oC

Note:
1. Reverse recovery condition $I_F=0.5A$, $I_R=1.0A$, Irr=0.25A.
2. Measured at 1.0 MHz and applied voltage of $4.0V_{dc}$
3. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area